

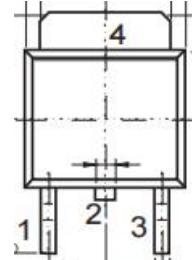
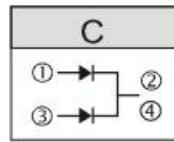
**TO-252 Schottky Barrier Rectifier Diode 肖特基势垒整流二极管****■Features 特点**

High surge current capability 高浪涌电流能力

Low forward voltage drop 低正向压降

High reliability 高可靠性

Case 封装:TO-252

**■Maximum Rating 最大额定值**

(TA=25°C unless otherwise noted 如无特殊说明, 温度为 25°C)

| Characteristic 特性参数              | Symbol 符号           | MBRD 2045 | MBRD 2060 | MBRD 20100     | MBRD 20150 | MBRD 20200 | Unit 单位 |
|----------------------------------|---------------------|-----------|-----------|----------------|------------|------------|---------|
| Peak Reverse Voltage 反向峰值电压      | V <sub>RRM</sub>    | 45        | 60        | 100            | 150        | 200        | V       |
| DC Reverse Voltage 直流反向电压        | V <sub>R</sub>      | 45        | 60        | 100            | 150        | 200        | V       |
| RMS Reverse Voltage 反向电压均方根值     | V <sub>R(RMS)</sub> | 32        | 42        | 70             | 105        | 140        | V       |
| Forward Rectified Current 正向整流电流 | I <sub>F</sub>      |           |           | 20             |            |            | A       |
| Peak Surge Current 峰值浪涌电流        | I <sub>FSM</sub>    |           |           | 175            |            |            | A       |
| Thermal Resistance J-A 结到环境热阻    | R <sub>θJA</sub>    |           |           | 8              |            |            | °C/W    |
| Junction Temperature 结温          | T <sub>J</sub>      |           |           | 150            |            |            | °C      |
| Storage Temperature 储藏温度         | T <sub>stg</sub>    |           |           | -55 to +150 °C |            |            | °C      |

**■Electrical Characteristics 电特性**

(TA=25°C unless otherwise noted 如无特殊说明, 温度为 25°C)

| Characteristic 特性参数     | Symbol 符号                       | MBRD 2045 | MBRD 2060 | MBRD 20100 | MBRD 20150 | MBRD 20200 | Unit 单位 | Condition 条件                     |
|-------------------------|---------------------------------|-----------|-----------|------------|------------|------------|---------|----------------------------------|
| Forward Voltage 正向电压    | V <sub>F</sub>                  | 0.55      | 0.70      | 0.85       | 0.9        |            | V       | I <sub>F</sub> =20A              |
| Reverse Current 反向电流    | I <sub>R(25°C)</sub><br>(125°C) | 0.1<br>5  |           | 0.02<br>2  |            |            | mA      | V <sub>R</sub> =V <sub>RRM</sub> |
| Diode Capacitance 二极管电容 | C <sub>D</sub>                  |           |           | 500        |            |            | pF      | V <sub>R</sub> =4V,<br>f=1MHz    |

## ■Typical Characteristic Curve 典型特性曲线

FIG.1-TYPICAL FORWARD CURRENT DERATING CURVE

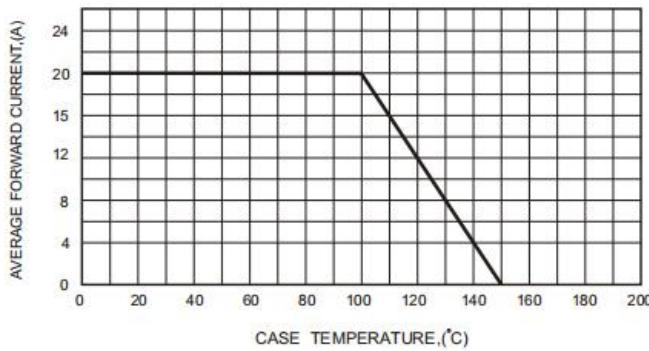


FIG.3-MAXIMUM NON-REPETITIVE FORWARD SURGE CURRENT

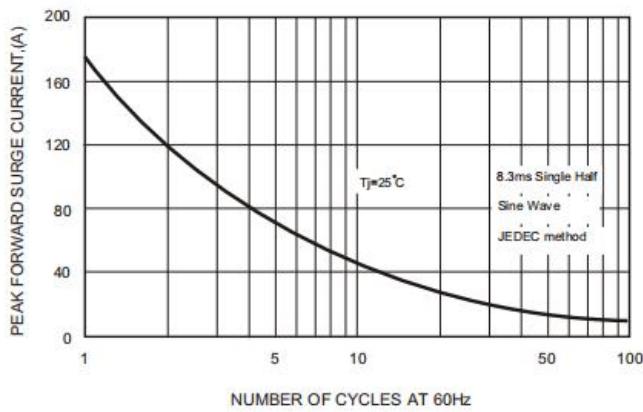


FIG.4-TYPICAL JUNCTION CAPACITANCE

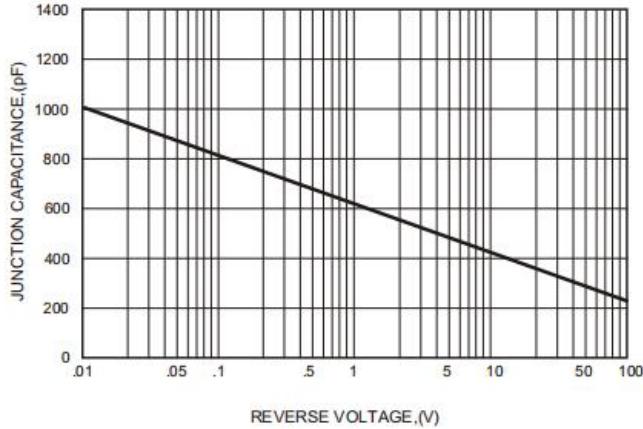


FIG.2-TYPICAL FORWARD CHARACTERISTICS

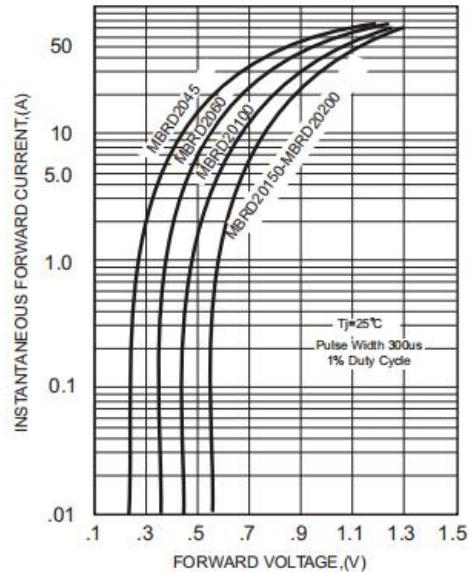
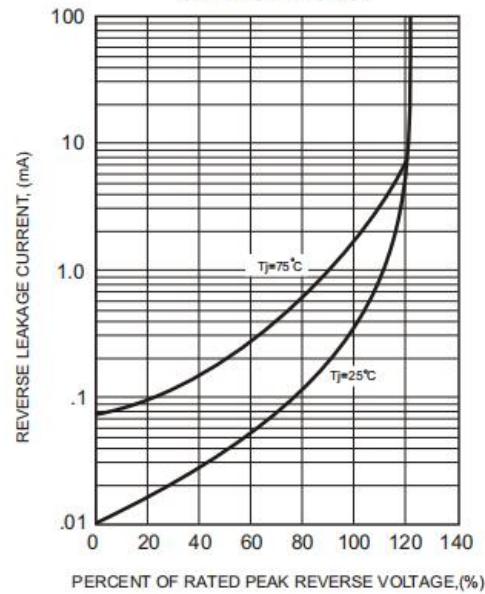


FIG.5 - TYPICAL REVERSE CHARACTERISTICS



■Dimension 外形封装尺寸

TO-252

Unit: mm

